



ZVN0545G

SOT223 N-CHANNEL ENHANCEMENT MODE VERTICAL DMOS FET

Product Summary

BV _{DSS}	Rds(on)	I _D T _A = +25°C	
450V	50Ω @ V _{GS} = 10V	140mA	

Description and Applications

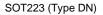
This MOSFET is designed to minimize the on-state resistance yet maintain superior switching performance, making it ideal for highefficiency power-management applications.

Features and Benefits

- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

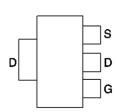
Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)

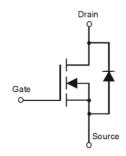




Top View



Pinout - Top View



Equivalent Circuit

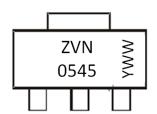
Ordering Information (Note 4)

Orderable Part Number	Paakaga	Packing		
Orderable Part Number	Package	Qty.	Carrier	
ZVN0545GTA	SOT223 (Type DN)	1,000	Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



 $\begin{tabular}{ll} ZVN0545 = Product Type Marking Code \\ YWW = Date Code Marking \\ Y or \overline{Y} = Last Digit of Year (ex: 4 = 2024) \\ WW or \overline{W}W = Week Code (01 to 53) \\ \end{tabular}$



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		VDSS	450	٧
Gate-Source Voltage		Vgss	±20	V
Continuous Drain Current VGS = 10V T	A = +25°C	ΙD	140	mA
Pulsed Drain Current		I _{DM}	600	mA

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation	$T_A = +25^{\circ}C$	PD	2	W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BVDSS	450		_	V	$V_{GS} = 0V$, $I_{D} = 1mA$	
Zero Gate Voltage Drain Current	Inco		_	10	μΑ	$V_{DS} = 450V, V_{GS} = 0V$	
Zero Gate Voltage Dialii Current	IDSS		_	400	μΑ	V _{DS} =405V, V _{GS} =0V, T=+125°C (Note 6)	
Gate-Source Leakage	I _{GSS}		1	±20	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
ON CHARACTERISTICS	ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	1		3	V	$V_{DS} = V_{GS}$, $I_{D} = 1mA$	
Static Drain-Source On-State Resistance (Note 5)	RDS(ON)		1	50	Ω	V _{GS} = 10V, I _D = 100mA	
On-State Drain Current (Note 5)	I _{D(ON)}	150	1	_	mA	V _{DS} =25V, V _{GS} =10V	
Forward Transconductance (Notes 5 and 6)	g fs	100	_	_	mS	V _{DS} =25V,I _D =100mA	
DYNAMIC CHARACTERISTICS (Note 6)							
Input Capacitance	Ciss		_	70	pF		
Output Capacitance	Coss	1	_	10	pF	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz	
Reverse Transfer Capacitance	Crss	_	_	4	pF		
Turn-On Delay Time (Note 7)	t _{D(ON)}	_	_	7	ns		
Turn-On Rise Time (Note 7)	t _R	_	_	7	ns],, osy, i, 1001	
Turn-Off Delay Time (Note 7)	tD(OFF)	_	_	16	ns	$V_{DD} = 25V$, $I_{D}=100$ mA	
Turn-Off Fall Time (Note 7)	tF	_	_	10	ns	1	

Notes:

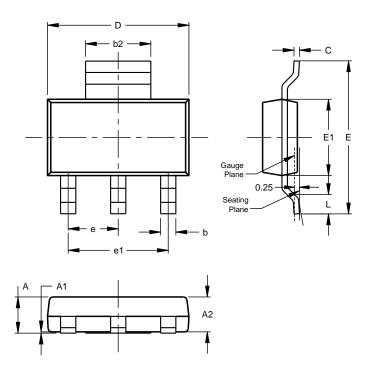
- 5. Measured under pulsed conditions. Width=300 μ s. Duty cycle \leq 2%.
- 6. Sample test. 7. Switching times measured with 50Ω source impedance and <5ns rise time on a pulse generator.



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)

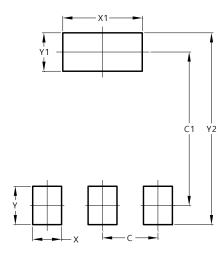


SOT223 (Type DN)					
Dim	Min	Max	Тур		
Α		1.70			
A 1	0.01	0.15			
A2	1.50	1.68	1.60		
b	0.60	0.80	0.70		
b2	2.90	3.10			
С	0.20	0.32			
D	6.30	6.70			
Е	6.70	7.30			
E1	3.30	3.70			
е			2.30		
e1			4.60		
L	0.85				
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)		
С	2.30		
C1	6.40		
Х	1.20		
X1	3.30		
Y	1.60		
Y1	1.60		
Y2	8.00		



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